

# QH12TZ600Q Qspeed<sup>™</sup> Family

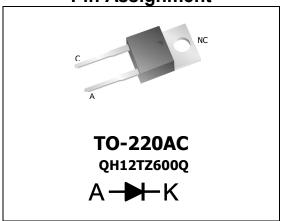
# Tintegrations<sup>™</sup>

600 V, 12 A H-Series SiC Replacement Diode for Automotive

## **Product Summary**

${ m I}_{\sf F(AVG)}$	12	Α
RRM	600	V
Q <sub>RR</sub> (Typ at 125 °C)	30	nC
I <sub>RRM</sub> (Typ at 125 °C)	2.2	Α
Softness t <sub>B</sub> /t <sub>A</sub> (Typ at 125 °C)	0.65	

## Pin Assignment



## **RoHS Compliant**

Package uses Lead-free plating and Green mold compound. Halogen free per IEC 61249-2-21.

## **General Description**

This device has the lowest  $Q_{RR}$  of any 600 V silicon diode. Its recovery characteristics increase efficiency, reduces EMI and eliminates snubbers. Replaces SiC diodes for similar efficiency performance in high switching frequency applications.

## **Applications**

- Power Factor Correction boost diode in on-board charger
- · Output rectifier of on-board charger

#### **Features**

- Low QRR, low IRRM, low tRR
- High dI<sub>F</sub>/dt capable (1000 A / μs)
- Soft recovery
- AEC-Q101 qualified
- Fab, assembly and test certified to IATF 16949

### **Benefits**

- Increases efficiency
  - Eliminates need for snubber circuits
  - Reduces EMI filter component size & count
- · Enables extremely fast switching

## **Absolute Maximum Ratings**

Absolute maximum ratings are the values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Symbol	Parameter	Conditions	Rating	Units
$V_{RRM}$	Peak repetitive reverse voltage	T <sub>J</sub> = 25 °C	600	V
$I_{\text{F(AVG)}}$	Average forward current	T <sub>J</sub> = 150 °C, T <sub>C</sub> = 90 °C	12	Α
$I_{FSM}$	Non-repetitive peak surge current	60 Hz, ½ cycle, T <sub>C</sub> = 25 °C	100	Α
$I_{FSM}$	Non-repetitive peak surge current	$1/2$ cycle of t = 28 $\mu$ s Sinusoid, $T_C$ = 25 °C	350	Α
T <sub>J</sub>	Operating junction temperature range		-55 to 150	°C
$T_{STG}$	Storage temperature		-55 to 150	°C
	Lead soldering temperature	Leads at 1.6 mm from case, 10 sec	300	°C
$V_{ISOL}$	Isolation voltage (leads-to-tab)	AC, TO-220	2500	V
$P_D$	Power dissipation	T <sub>C</sub> = 25 °C	61	W

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## **Thermal Resistance**

Symbol	Resistance from:	Conditions	Rating	Units
$R_{\theta JA}$	Junction to ambient	TO-220	62	°C/W
$R_{\theta JC}$	Junction to case		2.05	°C/W

Electrical Specifications at T<sub>J</sub>= 25 °C (unless otherwise specified)

Symbol	Parameter	Conditions		1in	Тур	Max	Units
DC Chara	acteristics			•			
т	Dovorco gurrent	V <sub>R</sub> = 600 V, T <sub>J</sub> = 25 °C		-	-	250	μΑ
$I_{R}$	Reverse current	V <sub>R</sub> = 600 V, T <sub>J</sub> = 125 °C		-	0.6	-	mA
M	Forward voltage	I <sub>F</sub> = 12 A, T <sub>J</sub> = 25 °C		-	2.65	3.1	V
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 12 A, T <sub>J</sub> = 150 °C		-	2.33	-	V
$C_{J}$	Junction capacitance	V <sub>R</sub> = 10 V, 1 MHz		-	34	-	pF
Dynamic	Characteristics	•			-	-	
_	Reverse recovery time	$dI/dt = 200 \text{ A}/\mu\text{s}$ $V_R = 400 \text{ V}, I_F = 12 \text{ A}$	T <sub>J</sub> = 25 °C	-	11.6	-	ns
$t_{RR}$			T <sub>J</sub> = 125 °C	-	20.5	-	ns
0	Devence receivemy change	dI/dt = 200 A/μs	T <sub>J</sub> = 25 °C	-	9.2	14	nC
$Q_{RR}$	Reverse recovery charge	$V_R = 400 \text{ V}, I_F = 12 \text{ A}$	T <sub>J</sub> = 125 °C	-	30	-	nC
т	Maximum reverse	a., a. = = 0 0 1 1 p. 0	T <sub>J</sub> = 25 °C	-	1.27	1.8	Α
$I_{RRM}$	recovery current		T <sub>J</sub> = 125 °C	-	2.2	-	Α
	Softness factor = $\frac{t_B}{t_A}$	dI/dt = 200 A/μs	T <sub>J</sub> = 25 °C	-	0.6	-	
S		$V_R = 400 \text{ V}, I_F = 12 \text{ A}$	T <sub>J</sub> = 125 °C	-	0.65	-	

**Note to component engineers**: H-Series diodes employ Schottky technologies in their design and construction. Therefore, Component Engineers should plan their test setups to be similar to those for traditional Schottky test setups. (For additional details, see Application Note AN-300.)

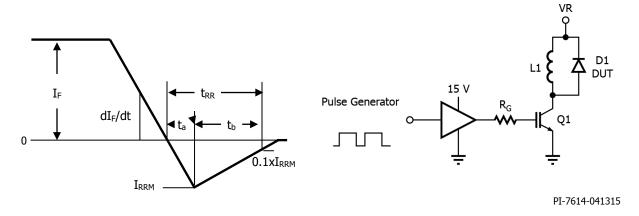
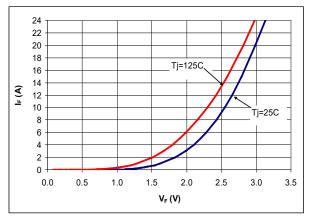


Figure 1. Reverse Recovery Definitions.

Figure 2. Reverse Recovery Test Circuit.

## Electrical Specifications at $T_1$ = 25 °C (unless otherwise specified)



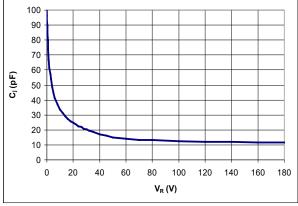
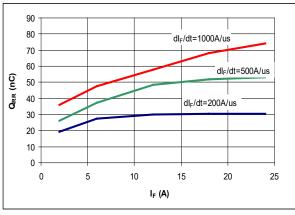


Figure 3. Typical I<sub>F</sub> vs. V<sub>F.</sub>

Figure 4. Typical C<sub>J</sub> vs. V<sub>R.</sub>



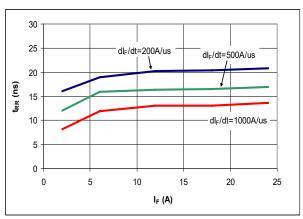
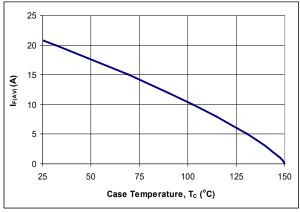


Figure 5. Typical  $Q_{RR}$  vs.  $I_F$  at  $T_J$  = 125 °C.

Figure 6. Typical  $t_{RR}$  vs.  $I_F$  at  $T_J$  = 125 °C.



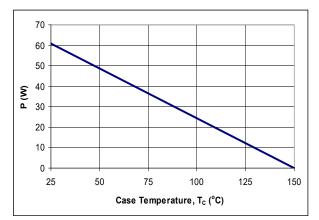


Figure 7. DC Current Derating Curve.

Figure 8. Power Derating Curve.

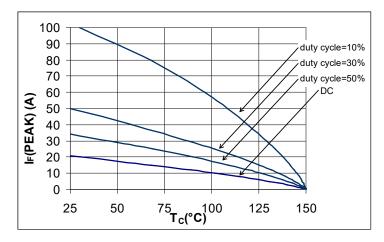


Figure 9.  $I_F(PEAK)$  vs.  $T_{C_r}$  f = 70 kHz.

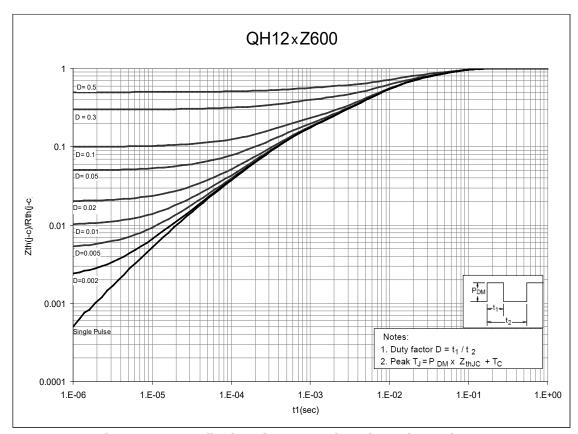
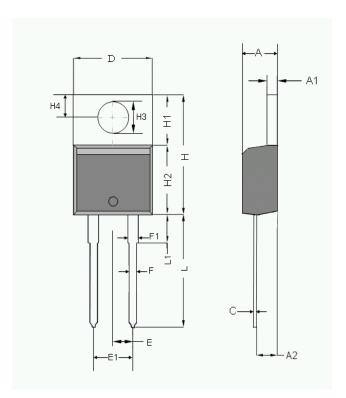


Figure 10. Normalized Maximum Transient Thermal Impedance.

## **Dimensional Outline Drawings**

#### TO-220AC



	Millimeters		
Dim	MIN	MAX	
Α	4.32	4.70	
<b>A1</b>	1.14	1.40	
A2	2.03	2.79	
С	0.34	0.610	
D	9.65	10.67	
E	2.49	2.59	
E1	4.98	5.18	
F	0.508	1.016	
F1	1.14	1.78	
Н	14.71	16.51	
H1	5.84	6.795	
H2	8.40	9.00	
Н3	3.53	3.96	
H4	2.54	3.05	
L	12.70	14.22	
L1	-	6.35	

Mechanical Mounting Method	Maximum Torque / Pressure specification
Screw through hole in package tab	1 Newton Meter (nm) or 8.8 inch-pounds (lb-in)
Clamp against package body	12.3 kilogram-force per square centimeter (kgf/cm²) or 175 lbf/in²

**Soldering time and temperature:** This product has been designed for use with high-temperature, lead-free solder. The component leads can be subjected to a maximum temperature of 300 °C, for up to 10 seconds. See Application Note AN-303, for more details.

## **Ordering Information**

Part Number	Package	Packing
QH12TZ600Q	TO-220AC	50 units/tube

The information contained in this document is subject to change without notice.



## QH12TZ600Q

Revision	Notes	Date
1.0	Code A release.	01/21



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